



Nanotechnologies and innovations in the Republic of Moldova

Ion Tiginyanu
Academy of Sciences of Moldova
tiginyanu@asm.md

Outline

- 1. Reforms in science in the Republic of Moldova**
- 2. Innovative system in Moldova**
- 3. Nanotechnologies in Moldova: main players**
- 4. Achievements in the field of nanotechnologies in the Republic of Moldova**
- 5. New State Program on Nanotechnologies and Nanomaterials in Moldova**
- 6. Conclusions**

REFORMS IN SCIENCE
in the Republic of Moldova

**The Low on Science and
Innovation**

Ratified by the Parliament on July 15, 2004

**The Low is a unique legislative document
which regulates relationships in the sphere
of science and innovation**

Reforms in Science and Innovation in Moldova

**Optimization of the network of research institutions
(38 institutes at present)**

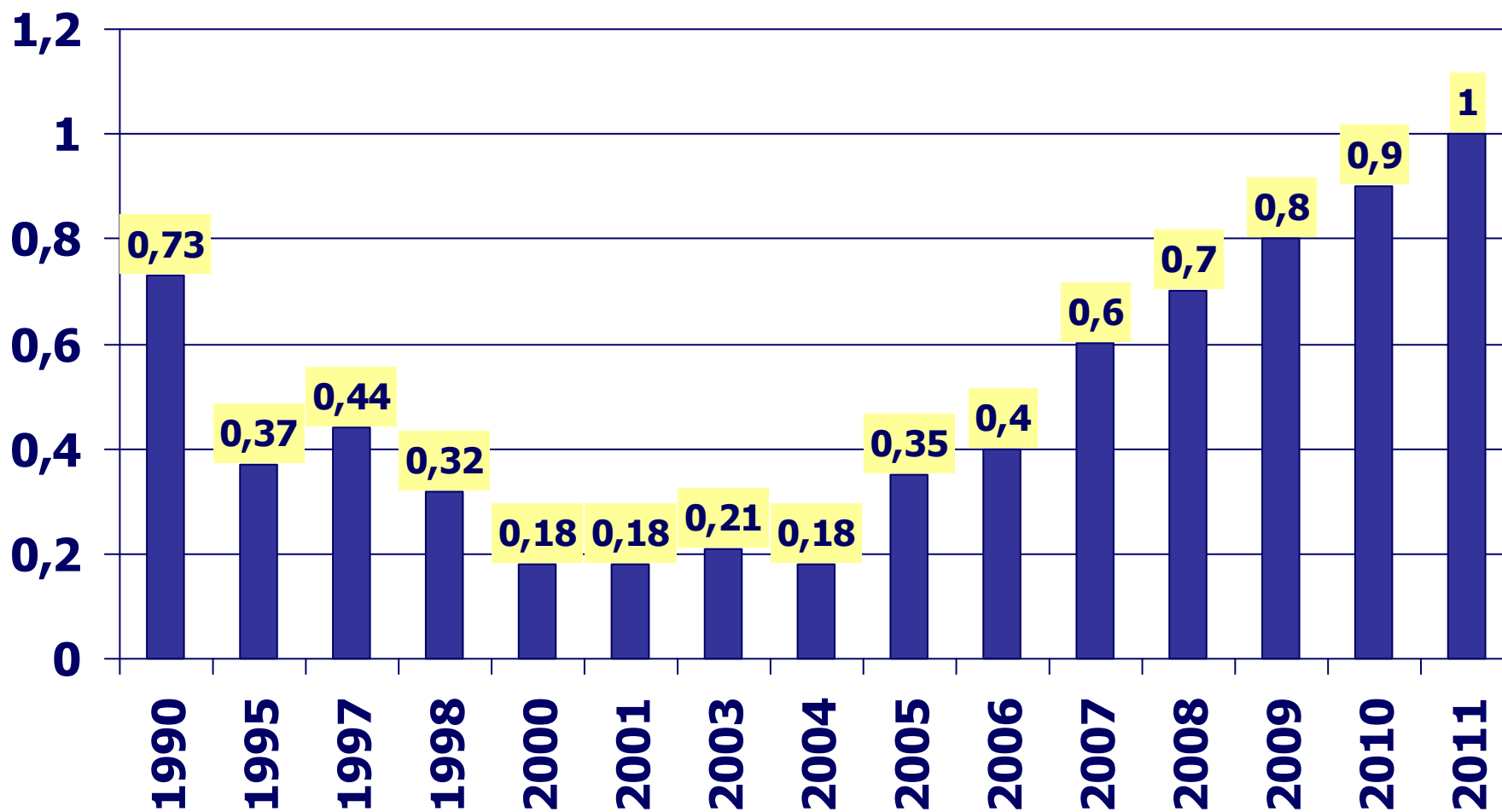
Accreditation of the research institutions

Promotion of new strategies and laws

- Strategy of Industrial Development of Moldova**
- Strategy of the Development of Agriculture**
- Strategy for the Development of Renewable Energy Sources**

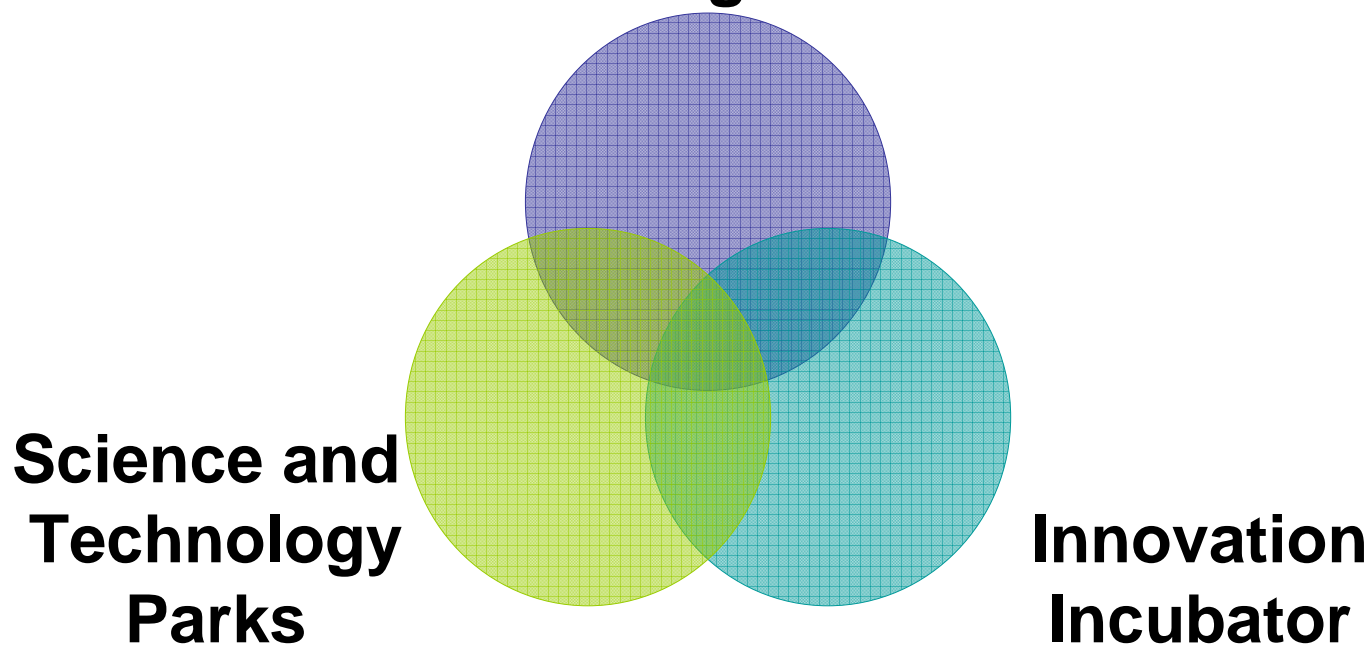
Law on Technology Parks and Business Incubators

Dynamics of Science Financing



Innovative system in Moldova

**Agency for Innovations
and Technological Transfer**



LAW ON TECHNOLOGY PARKS AND INNOVATIVE INCUBATORS
No. 138-XVI of 21.06.2007

Important peculiarities

1. Geographical freedom.

2. Fiscal and customs facilities:

- Exemption from payment of VAT (20 %) on goods and services imported from abroad;**
- Exemption from payment of VAT (20 %) on goods and services bought on the territory of the Republic of Moldova;**
- Exemption from payment of customs taxes (5 %) on imported goods and services.**

Scientific educational Cluster
of the Academy of Sciences of Moldova
„Univer SCIENCE”



Education through RESEARCH

PUBLIC INVESTORS

PRIVATE INVESTORS

**UNIVERSITY
of ASM**

**LYCEUM of ASM
for gifted
children**

**RESEARCHERS
IN ASM
INSTITUTES**

**STATE AND
PRIVATE
STUCTURES**

**SCIENTIFIC EDUCATIONAL
CLUSTER
„Univer SCIENCE”**

**BUSINESS IN
INNOVATION
MANAGEMENT**

**CENTER
for Graduate,
Post-graduate
Education
and Training**

**RESEARCH
INSTITUTIONS
of ASM**

**SPECIALISTS
IN
LABORATORIES
OF ANALYSIS
AND EXPERTISE**

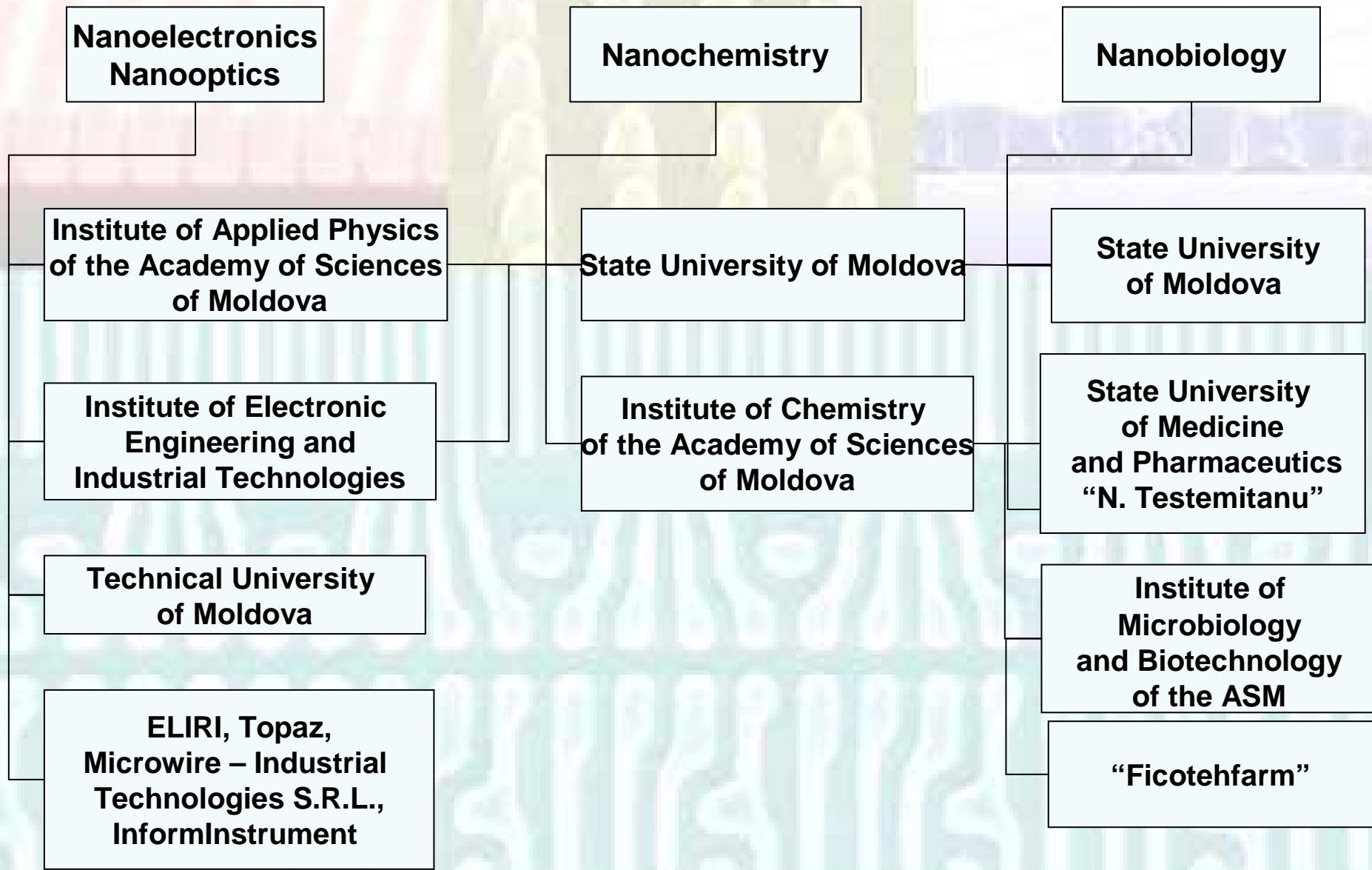
**RESEARCH AND EDUCATION MEDIUM FAVORABLE FOR KEEPING ON THE SUPPLY
OF PERSONNEL FOR RESEARCH AND TECHNOLOGICAL TRANSFER STRUCTURES**

Nucleus of the CLUSTER

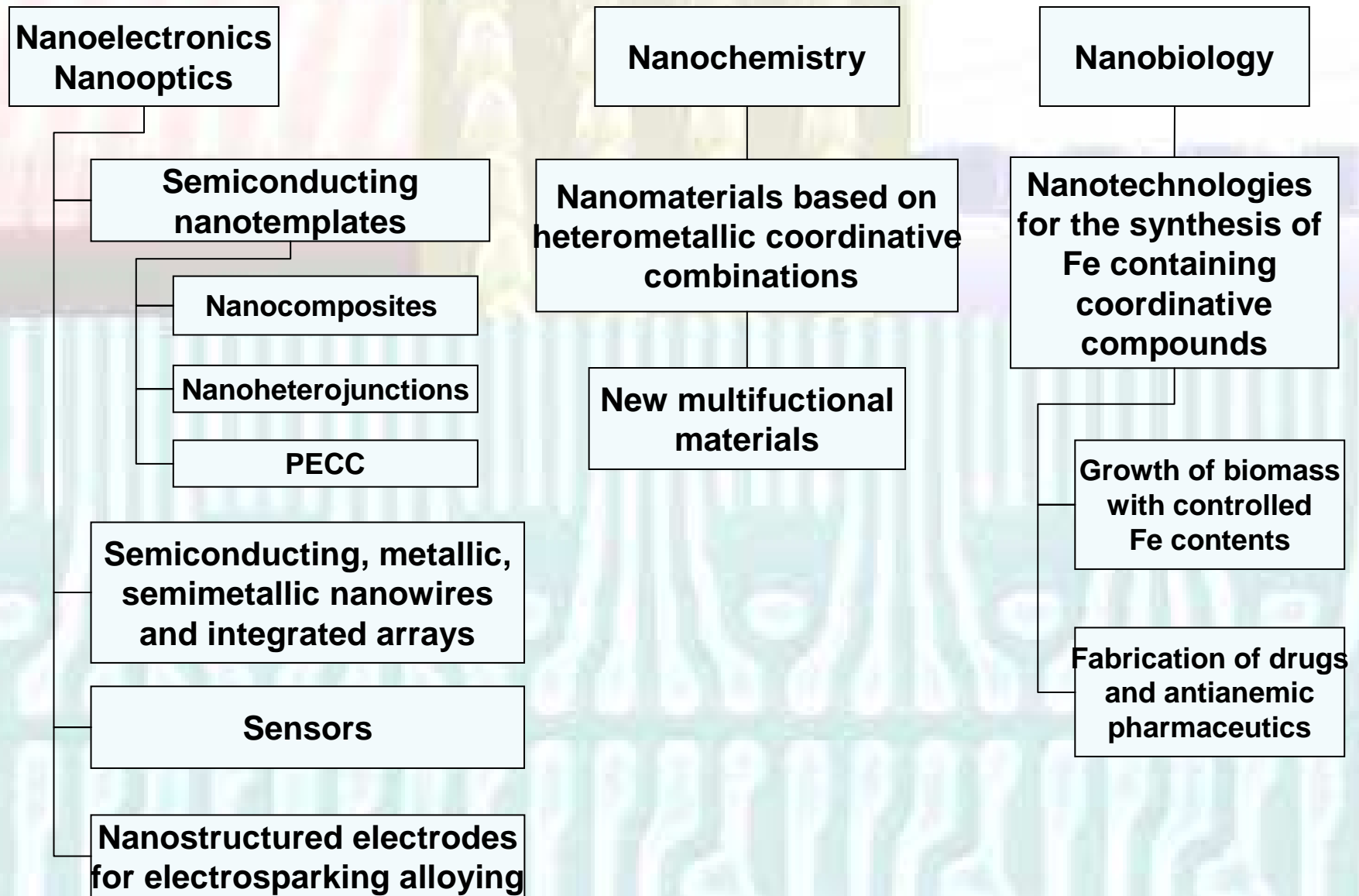
- ❖ **Lyceum of ASM for gifted children;**
- ❖ **University of ASM;**
- ❖ **Research institutions;**
- ❖ **Science and Technology Parks;**
- ❖ **Innovative incubator.**

Nanotechnologies in Moldova: Main players

Nanoscience and nanotechnology in Moldova



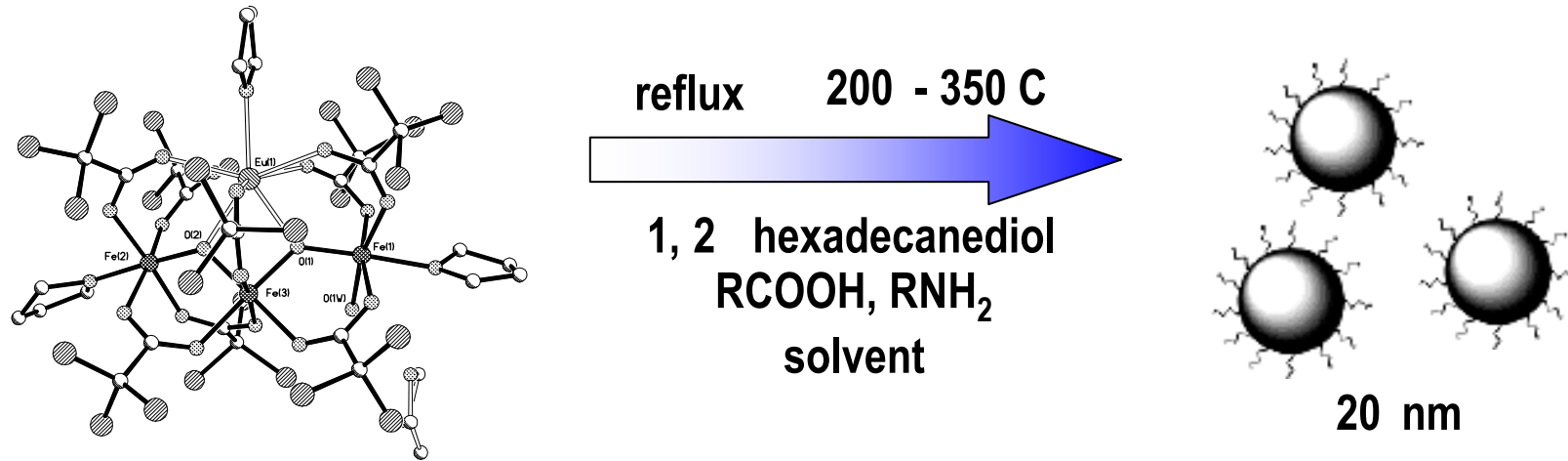
Nanoscience and nanotechnology in Moldova



Achievements in the field of nanotechnologies in the Republic of Moldova

Nanotechnologies in the Republic of Moldova

1. Chemical and electrochemical technologies for growth of clusters, nanocrystals, quantum dots etc.



2. Technologies for layer deposition, including epitaxy

GaN ZnO GaAs InP polymers

3. Methods for the fabrication of nanowires, nanostructures and integrated networks on their basis

metals semimetals semiconductors nanocomposites

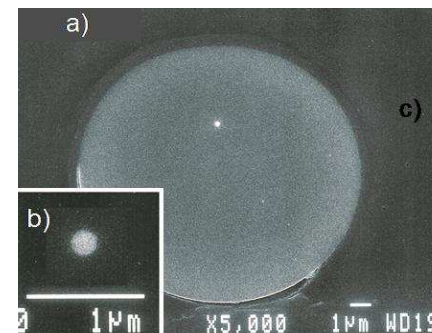
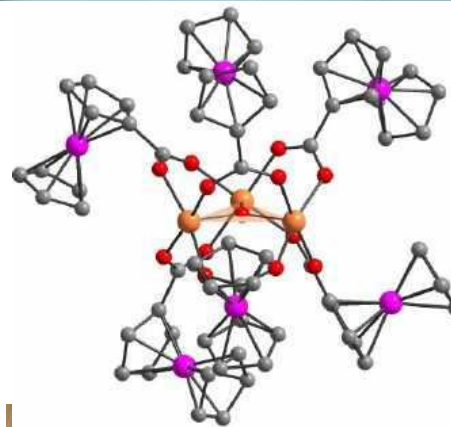
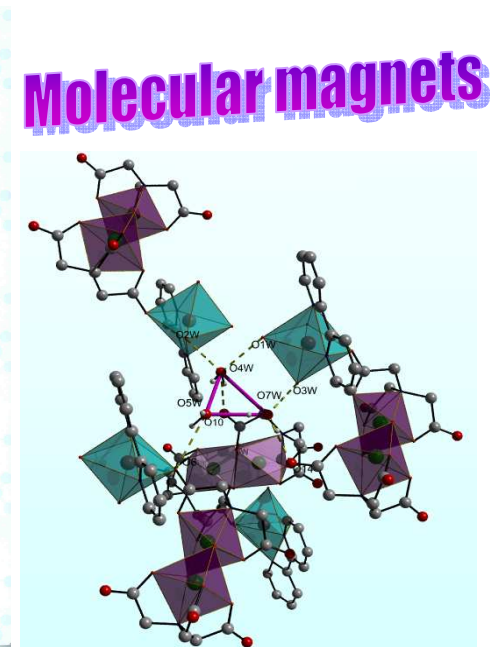
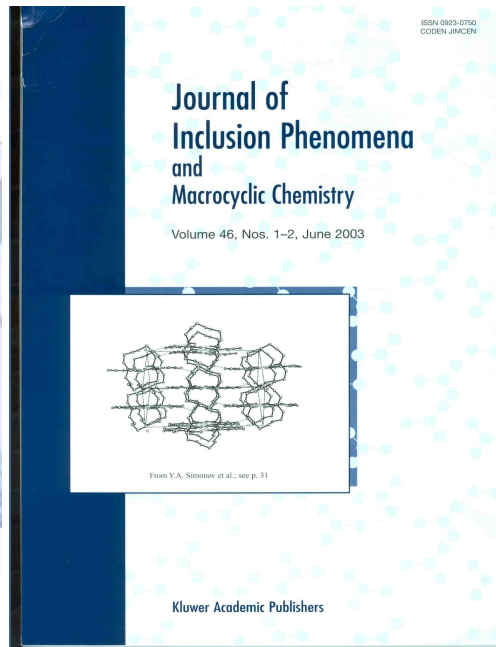
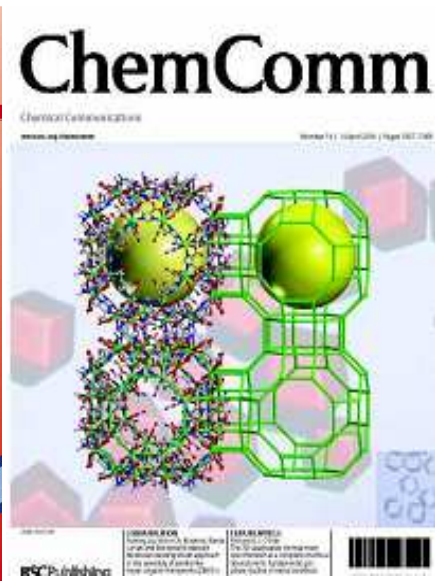
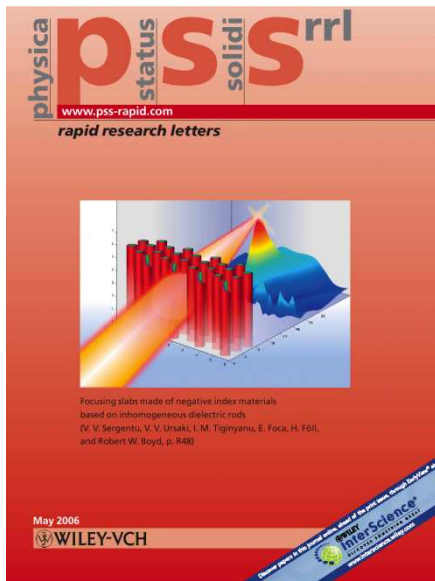
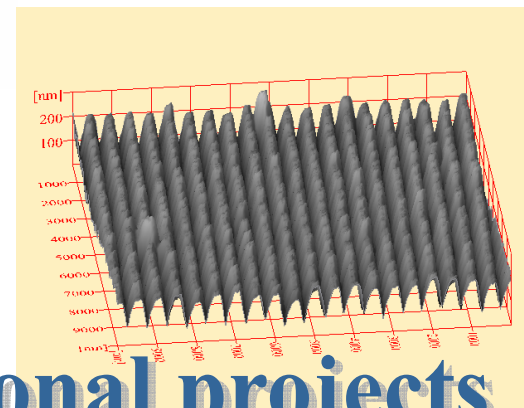
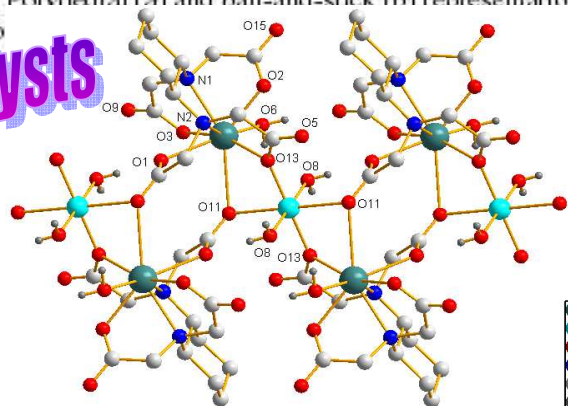


Figure 1. Polyhedral (a) and ball-and-stick (b) representations of the crystal structure of

Catalysts



30 international projects



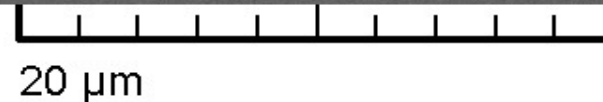
ELIRI Research Institute

**Metal
microwires**



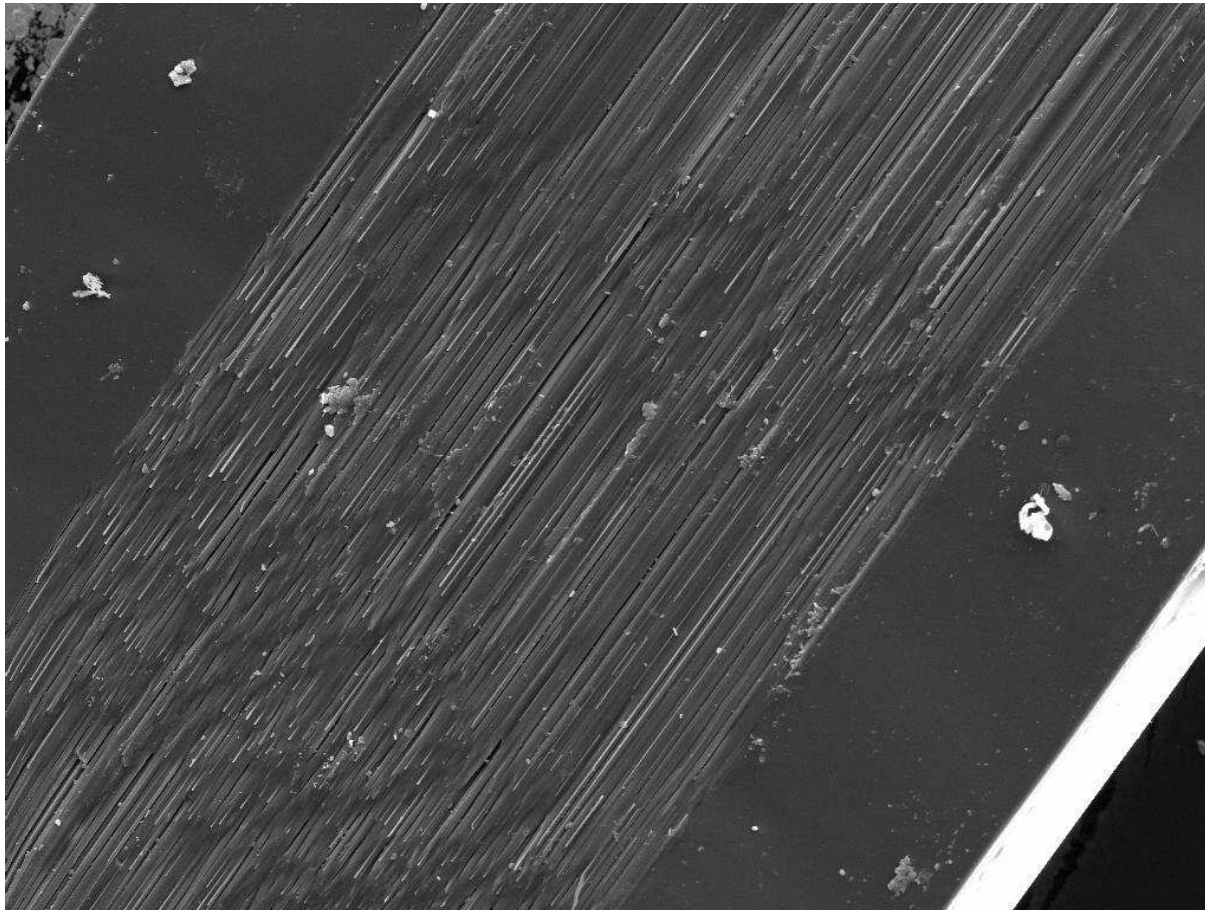
SEM MAG: 4.95 kx
HV: 20.0 kV

DET: SE Detector
DATE: 09/02/04

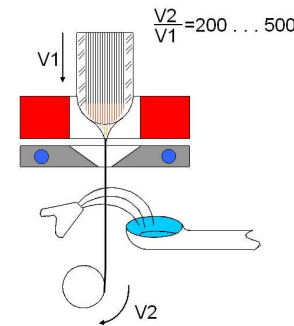


Vega ©Tescan

Micro-cable consisting of up to 600,000 nanowires in glass envelope



SEM MAG: 579 x DET: SE Detector
HV: 20.0 kV DATE: 05/27/08 200 μ m Vega ©Tescan UTM

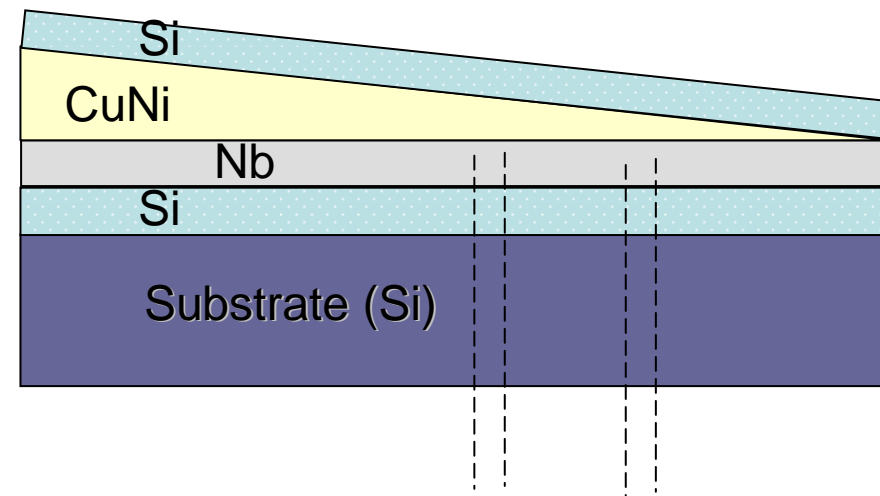
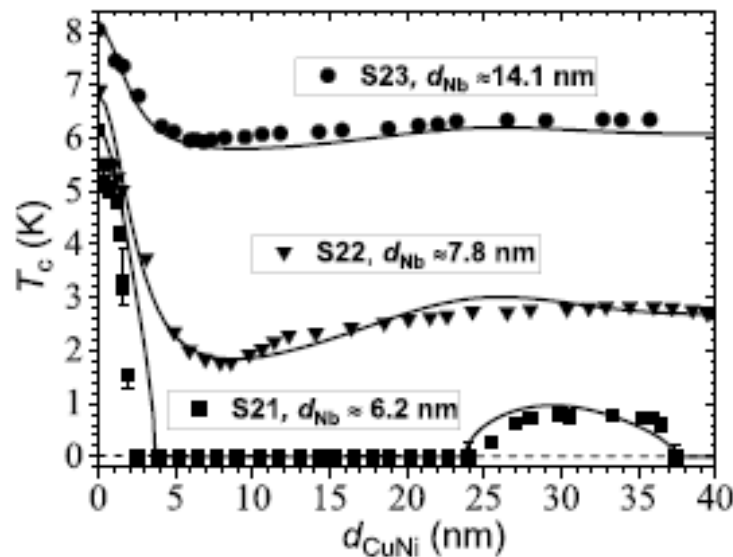


up to
600,000
nanowires





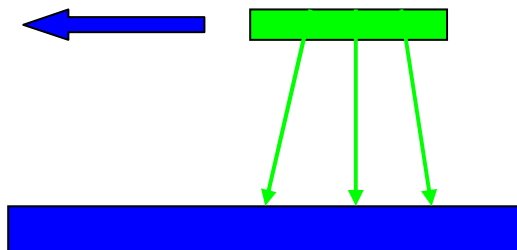
Experimental observation of the re-entrant superconductivity in Nb/Cu₄₁Ni₅₉ bilayers (V.I. Zdravkov, A.S.Sidorenko *et al.*, PRL 97, 057004, 2006)



Non monotonous $T_c(d_F)$
($d_{Nb} \approx 14.1$, and 8.3 nm),

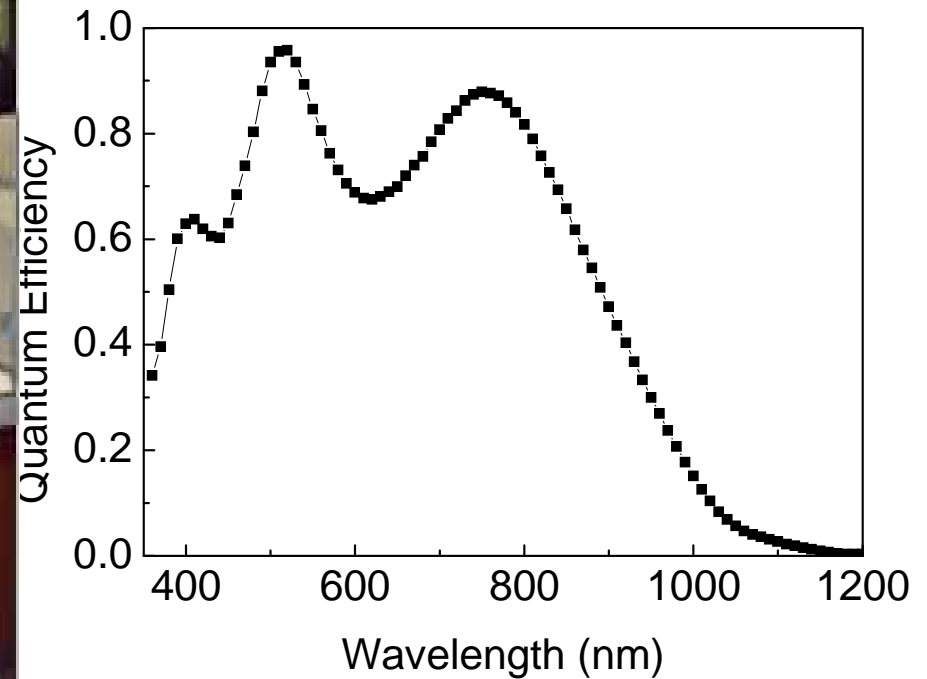
and re-entrant $T_c(d_F)$ behavior
for $d_{Nb} \approx 7.3$ nm $< \xi_s \sim 8$ nm.

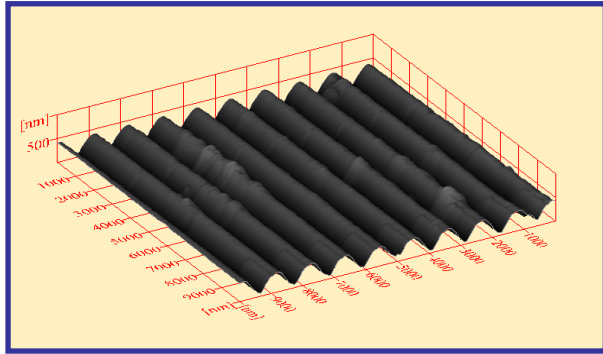
oving target:



Institute of Applied Physics State University of Moldova

n^+ ITO-SiO₂-nSi SOLAR CELLS OBTAINED BY SPRAY-PIROLISYS TECHNIQUE



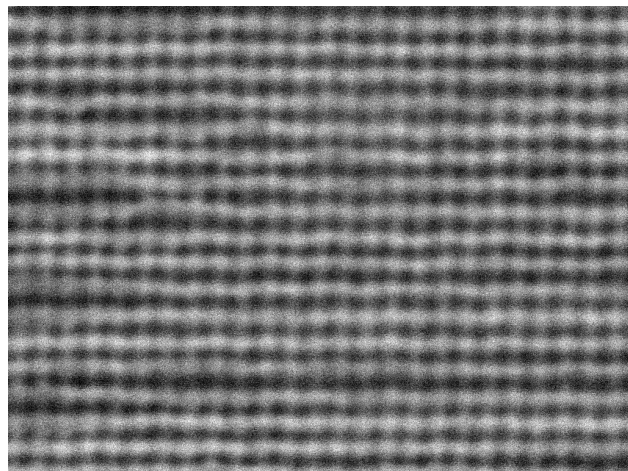


Diffraction grating: spatial frequency 1000 lines/mm

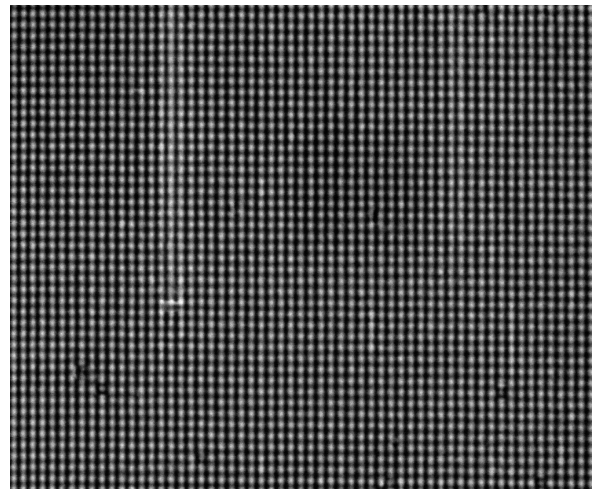
Fig. 1 Topography of holographic diffraction gratings patterns, constant of grating 1 μm .

Superimposed diffraction gratings: spatial frequency 2000 lines/mm

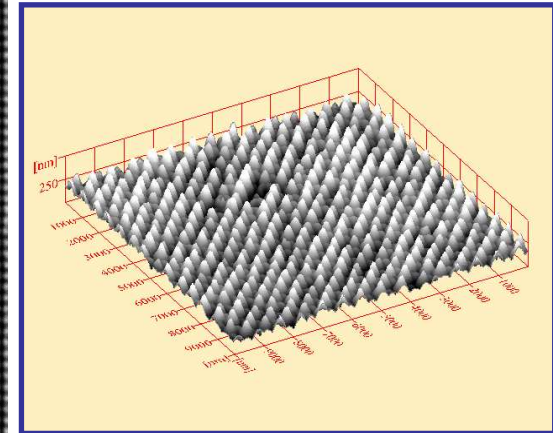
Fig.2,3 Superimposed gratings with grating constant 500 nm. (observed by Scanning Electron Microscope SEM and Atomic-Force Microscope AFM).



SEM MAG: 52.18 kx DET: SE Detector HV: 20.0 kV DATE: 07/05/05 2 μm Vega ©Tescan UTM



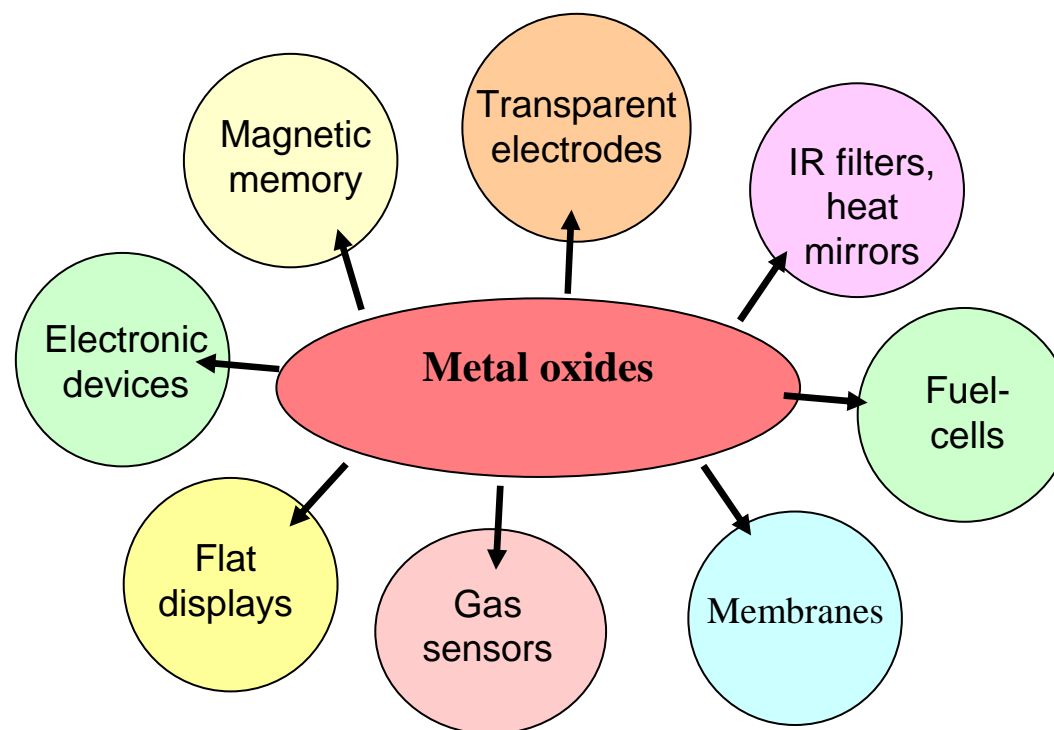
SEM MAG: 10.95 kx DET: SE Detector HV: 20.0 kV DATE: 03/18/05 10 μm Vega ©Tescan UTM



Diffraction grating: spatial frequency 4000 lines/mm

Fig. 4 Superimposed gratings, grating constant 250 nm. (observed by Scanning Electron Microscope (SEM))

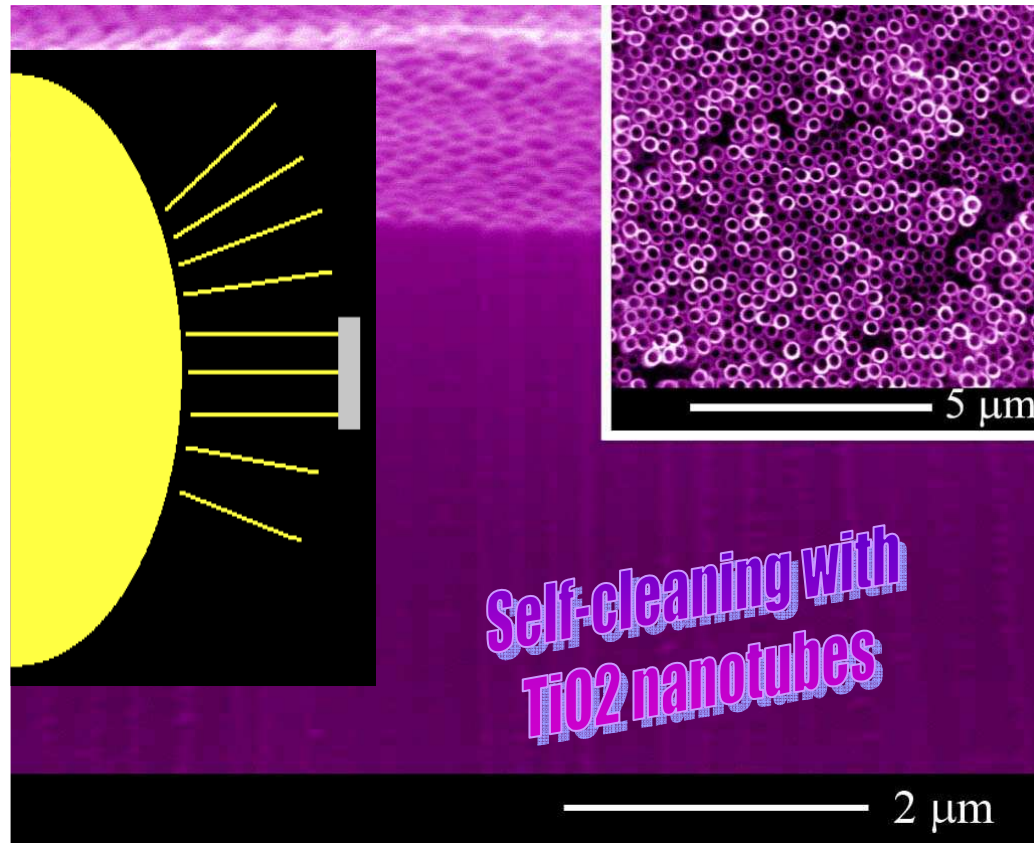
Metal oxides for various applications



SnO_2 and In_2O_3 - **Spray pyrolysis** (Dr. hab. Gh. Korotchenkov, TUM;
Prof. D.Sherban, Institute of Applied Physics and State University of Moldova)
 ZnO – **Chemical bath deposition** (Prof. T. Sisianu, Prof. D. Tsiulyanu,
Dr. O. Lupan, TUM)

Low cost and low power consuming ($P < 100$ mW) In_2O_3 and SnO_2 -based sensor prototypes for O_3 , CO , CH_4 , H_2 , smoke, fire, and vapors of organic solvents detection were developed.

National Center for Materials Study and Testing



www.ncmst.utm.md

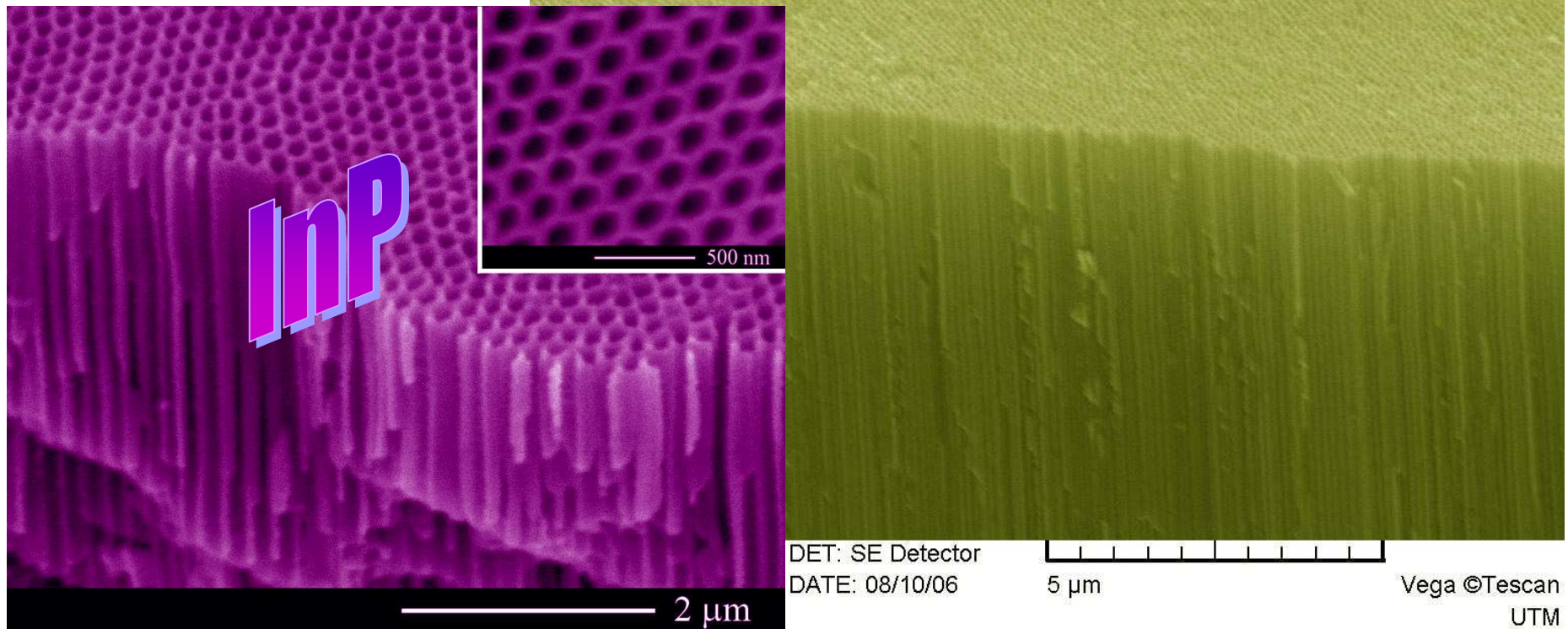
V. Sergentu, I. Tiginyanu, V. Ursaki et al
Physica Status Solidi – RRL, Vol. 2 (2008).

TiO_2 nanotubes
for photonics

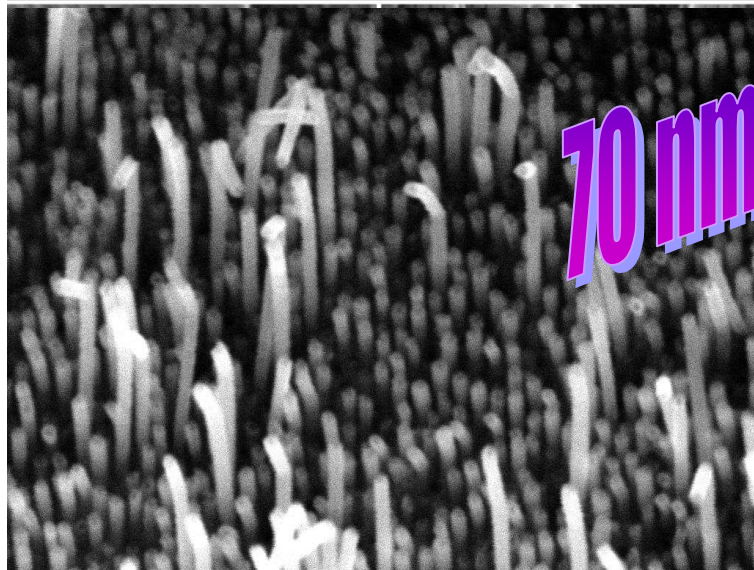
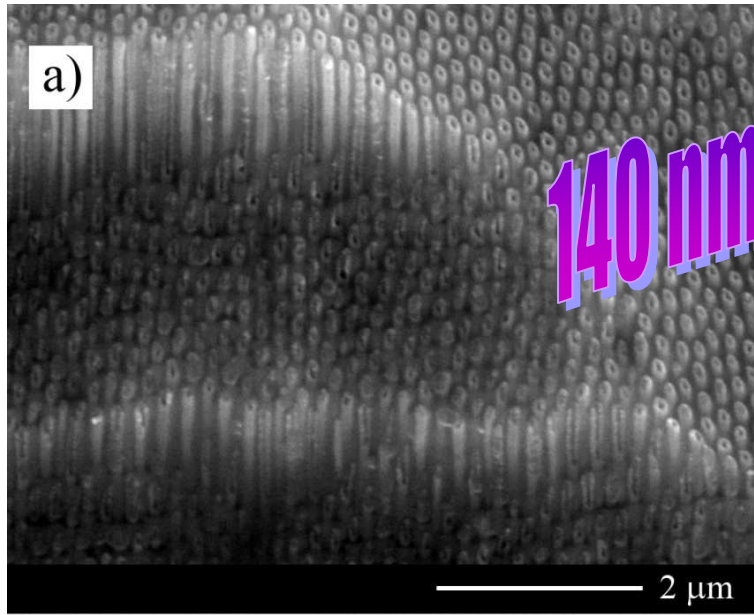


Nanotemplates with ordered nanochannels

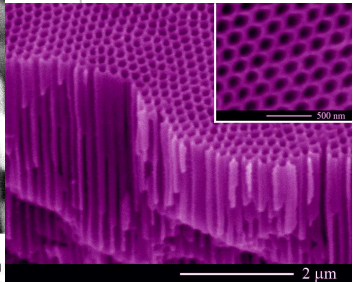
Environmentally-
friendly
approaches



*I.M. Tiginyanu et al, Physica Status Solidi (RRL), Vol. 1, issue 3, pp. 98-100 (2007);
Electrochemical and Solid-State Letters, Vol. 10 (11), pp. D127-D129 (2007).*



SEM MAG: 86.03 kx DET: SE Detector
 HV: 30.0 kV DATE: 04/06/07
 1 μm Vega ©Tescan UTM



NanoTechWeb.org

- ### LATEST NEWS ARTICLES
- ▶ Magnetic nanoparticles seek out artery plaques
 - ▶ Nanosheets get a better shot at the market
 - ▶ Nanotubes on the look out for new bone
 - ▶ Striped nanoparticles enter cells with ease
 - ▶ Nanotubes turn up the heat on cancer

- ### RELATED STORIES
- ▶ Nickel-filled carbon nanotubes line up for devices (December 2002)

- ### RELATED LINKS
- ▶ Ion Tiginyanu
 - ▶ Technical University of Moldova
 - ▶ Institute of Applied Physics, Academy of Sciences of Moldova

- ### RESTRICTED LINKS
- ▶ *Electrochemistry Communications* **10** 731

TECHNOLOGY UPDATE

Jun 23, 2008

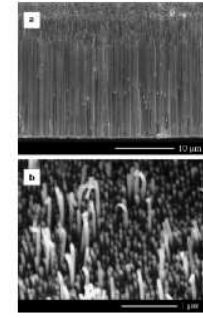
Salty water puts metal nanotubes in order

A new, simple technique to produce ordered arrays of metal nanotubes has been developed by scientists in Moldova. The method works by electroplating in conductive nanotemplates routinely fabricated by anodic etching of semiconductor substrates in salty water. The result could be important for making plasmonic devices, photonic crystals, catalysts for energy conversion and chemical and biological sensors.

Ion Tiginyanu and colleagues from the National Center for Materials Study and Testing have developed a cost-effective and environmentally friendly nanofabrication approach for making semiconductor nanotemplates.

The researchers showed that anodic etching of crystalline substrates of indium phosphide - a semiconductor compound used in modern electronics - in a neutral electrolyte based on an aqueous solution of sodium chloride leads to spatial nanostructuring of the material. In particular, it leads to the growth of self-organized ordered two-dimensional arrays of pores with transverse dimensions as low as 70 nm. "In fact, we have succeeded in producing high-quality nanotemplates by anodic etching of indium phosphide substrates in salty water from the Black Sea," Tiginyanu told *nanotechweb.org*.

Currently, two types of nanotemplates are widely used in nanofabrication: porous aluminium oxide and etched ion track membranes based either on inorganic materials or organic polymers. However, both of these materials have high resistivity and therefore only play a passive role in nanofabrication processes. "The great advantage of the semiconductor nanotemplates we used is their electrical conductivity, which can effectively be controlled during fabrication using light or applied electric fields, for example," said Tiginyanu.



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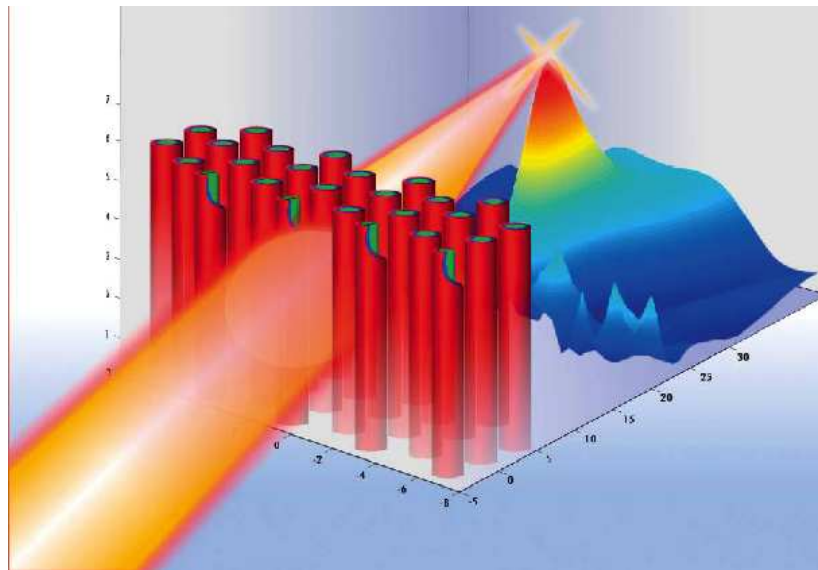
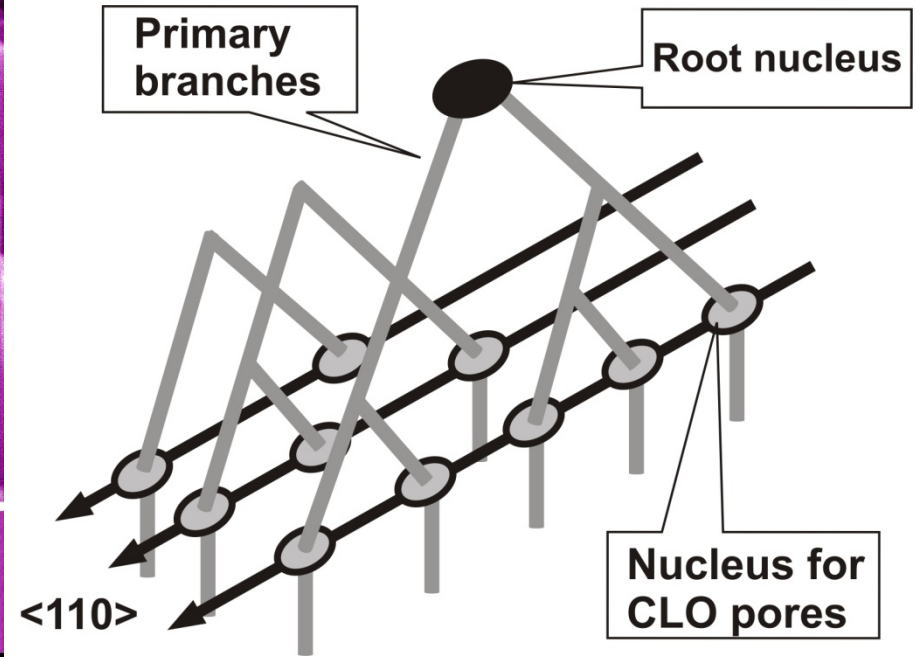
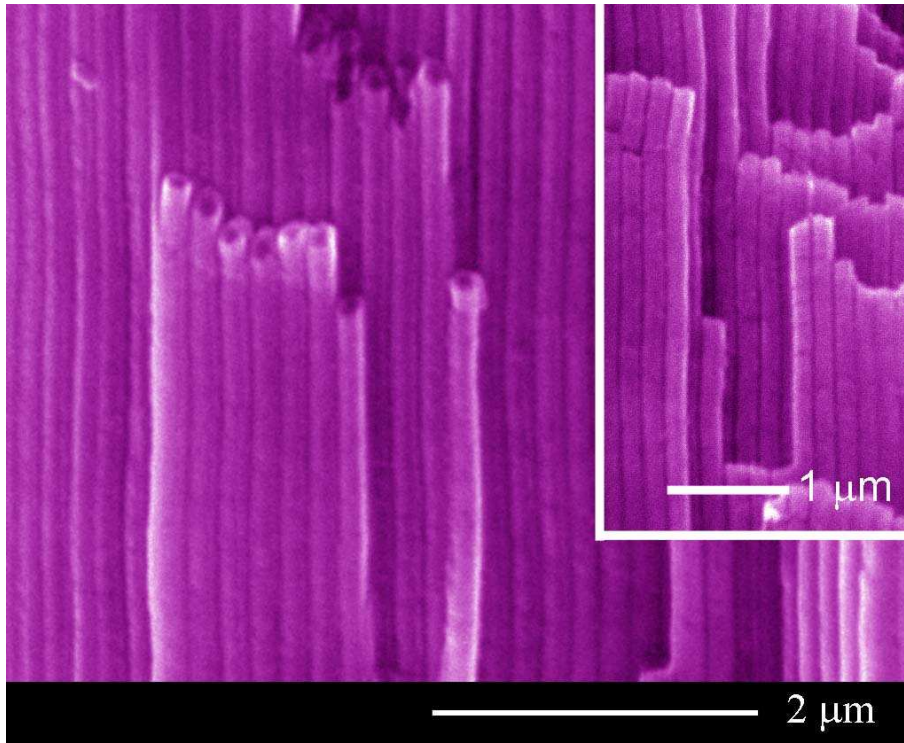
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STAIB
 20 Years
 INSTRUMENTS

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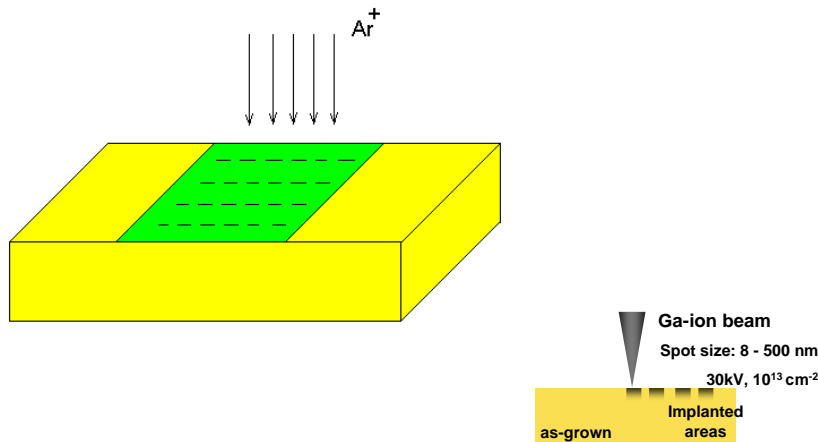
Corporate Partners



**Electrochemistry
Communications,
Vol. 10, 731-734 (2008)**

Surface Charge Lithography

1. Direct “writing” of the negative charge by focused ion beam (FIB)



Ion beam treatment

- 2-keV-Ar ions at the dose $3 \times 10^{12} \text{ cm}^{-2}$
- 30-keV Ga ions at the dose $6.6 \times 10^{12} \text{ cm}^{-2}$, beam current of 150 pA (penetration 14 nm), pixel format (1 pixel 30 nm)

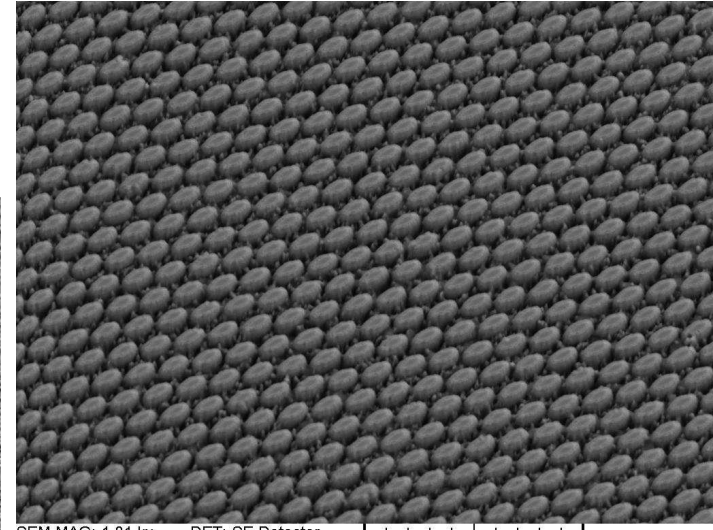
2. Photoelectrochemical etching of the FIB-treated structures

PEC etching was carried out in stirred 0.1 mol aqueous solution of KOH under in-situ ultraviolet (UV) illumination provided by focusing the radiation of a 350 W Hg lamp to a spot of about 5 mm in diameter on the GaN surface exposed to electrolyte.

In most cases we used MOCVD-grown n-GaN layers with electron concentration of $1.7 \times 10^{17} \text{ cm}^{-3}$, the density of dislocations was in the range of 10^9 - 10^{10} cm^{-2} .

Surface Charge Lithography

Gold Medal,
Pittsburgh,
2005

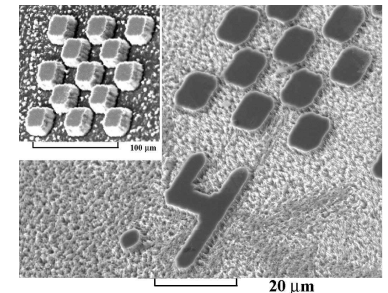
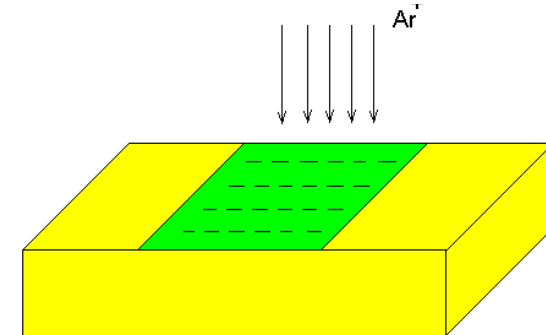


SEM MAG: 1.81 kx DET: SE Detector
HV: 20.0 kV DATE: 11/12/07 50 μm Vega ©Tescan UTM

M O L D O V A

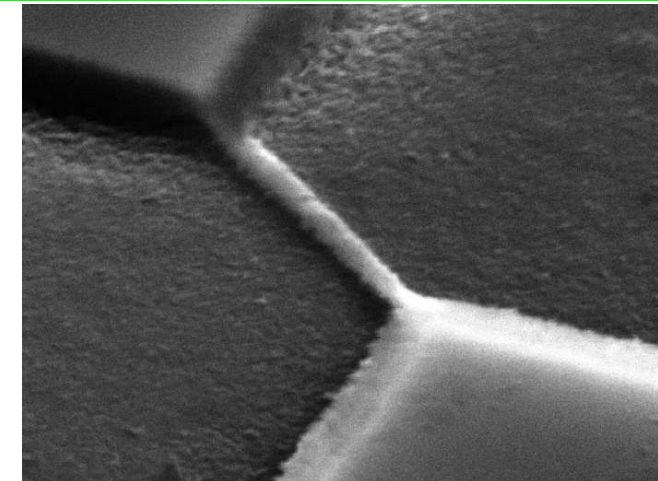
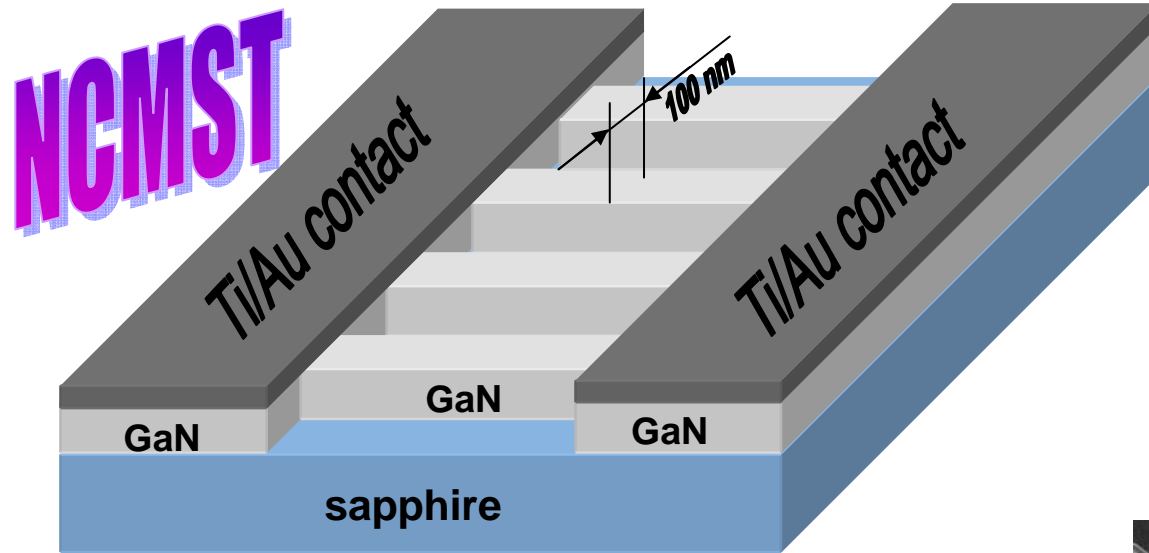
GaN

200 μm



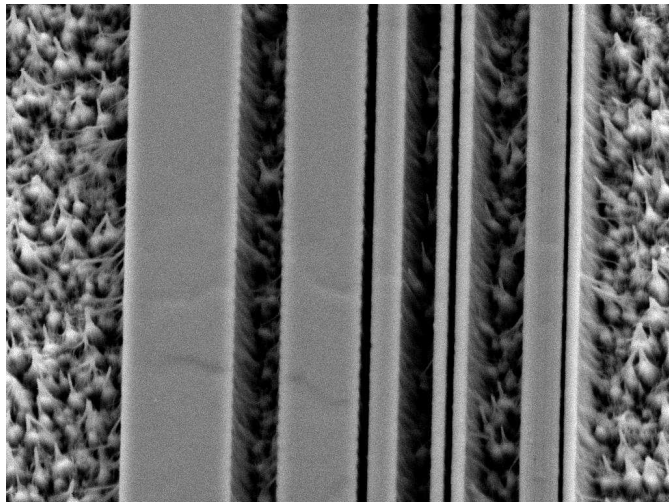
Applied Physics Letters, Vol. 86, 174102 (2005).

Fabrication of GaN nanowalls and nanowires

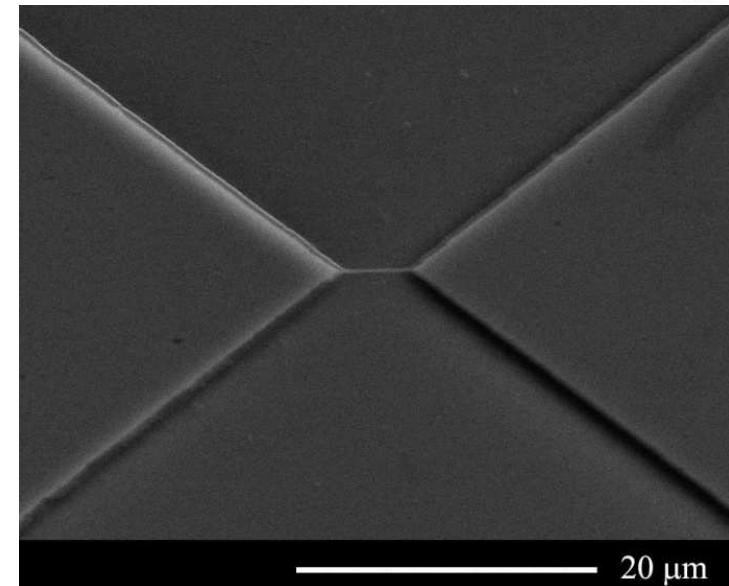
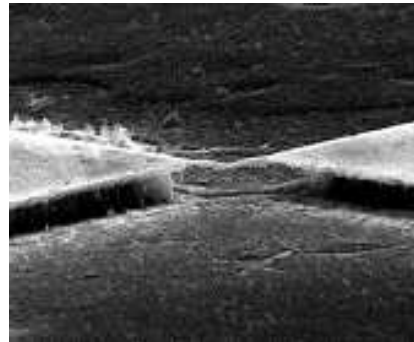


SEM MAG: 45.49 kx DET: SE Detector
HV: 30.0 kV DATE: 02/26/08 2 μm Vega ©Tescan UTM

Surface Charge Lithography



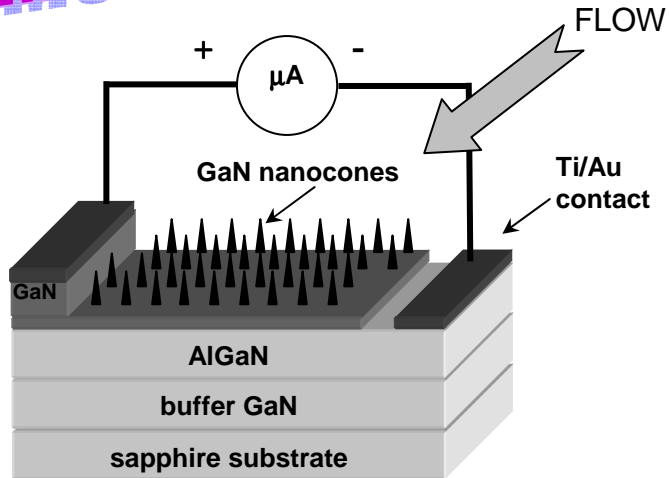
SEM MAG: 5.64 kx DET: SE Detector
HV: 20.0 kV DATE: 03/25/08 20 μm Vega ©Tescan UTM



Materials Letters, Vol. 62, p. 4576-4578 (2008).

GaN nanostructure based piezoelectric battery for self powered biosensors applications

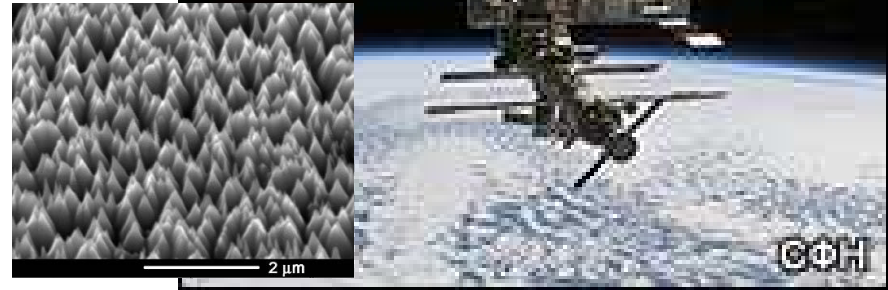
NCMST



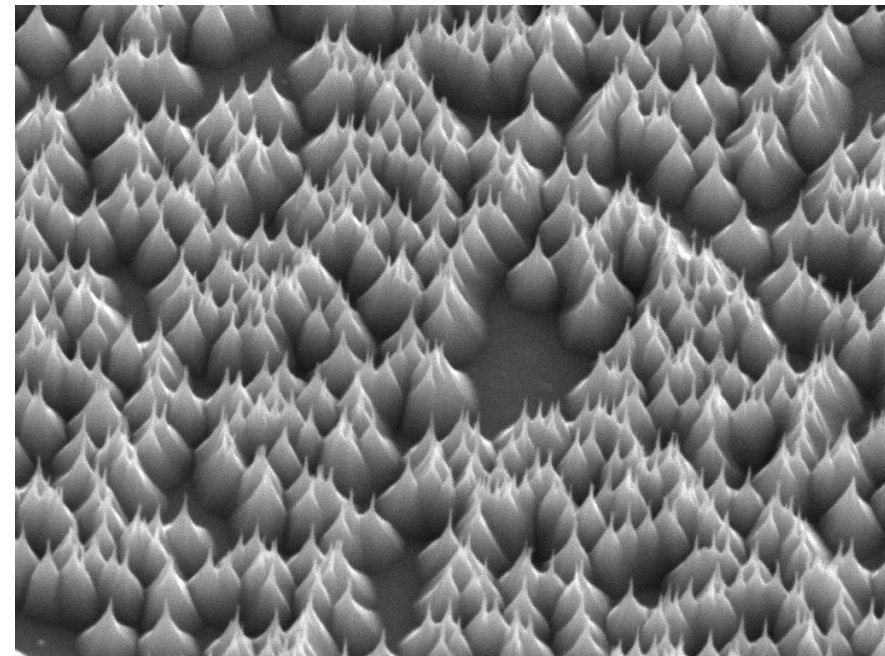
GaN Nanopyramids resist radiation

Applied Physics Letters, Vol. 90, 161908 (2007).

NanoTechWeb.org



<http://nanotechweb.org/articles/news/6/5/19/1>



SEM MAG: 16.66 kx DET: SE Detector HV: 20.0 kV DATE: 11/08/07 5 μm Vega ©Tescan UTM

New State Program on Nanotechnologies and Nanomaterials in Moldova

State Program on Nanotechnologies and Nanomaterials

Cluster 1. Novel nanocomposite, nanoporous and ordered nanostructured materials for optoelectronic and photonic applications

- **Development of 2D and 3D metallo-dielectric and metallo-semiconductor structures for electronic and photonic applications (Ion Tighineanu).**
- 2. Elaboration of nanocomposites based on organic-inorganic materials for luminescent and diffraction devices (Andrei Andriesh).**
- 3. New metalorganic nanoporous absorbent materials (Bourosh Paulina).**
- 4. Synthesis and characterization of thermal properties of new polymeric nanocomposite materials with high thermal stability (Ion Dranca).**

State Program on Nanotechnologies and Nanomaterials

Cluster 2. Technologies of thin films and multi-layer structures for applications in machine building and electronics

1. **Electrosparking technology of discrete chemo-thermal treatment of surfaces for anticorrosive protection of machine parts (Alexandru Balanici).**
2. **Electrodeposition of multi-layer nanocomposites and study of corrosive, tribological and magnetic properties for applications (Alexandru Dicusar).**
3. **Cost-effective technologies for growth of nanostructured ZnO films for photonic and nanoelectronic applications (Rusu Emil).**
4. **Elaboration of GaInP/GaAs(InP) nanostructured films by Vapor Phase Epitaxy for electronic applications (Leonid Gorceac).**

State Program on Nanotechnologies and Nanomaterials

Cluster 3. Novel materials for energy conversion and storage

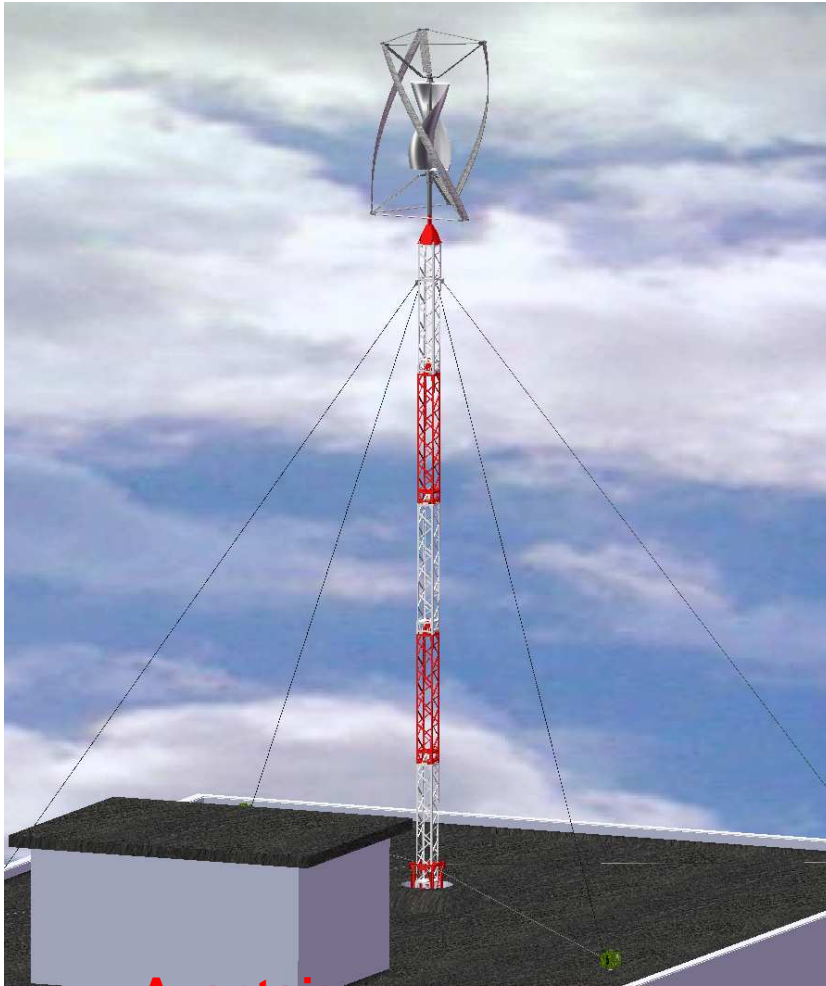
1. **Elaboration of nanostructured composites of lead and bismuth chalcogenides for energy conversion systems (Andrei Nicorici).**
2. **Semiconductor colloidal nanocrystals for applications in infra-red photoelectrical devices (Leonid Culiuc).**
3. **New nanometric multi-layer semiconductor structures for applications in technologies of energy conversion and storage (Igor Evtodiev).**

Prototipul industrial microhidrocentralei cu rotor hidrodinamic pentru conversia energiei cinetice a râului în energie electrică și mecanică



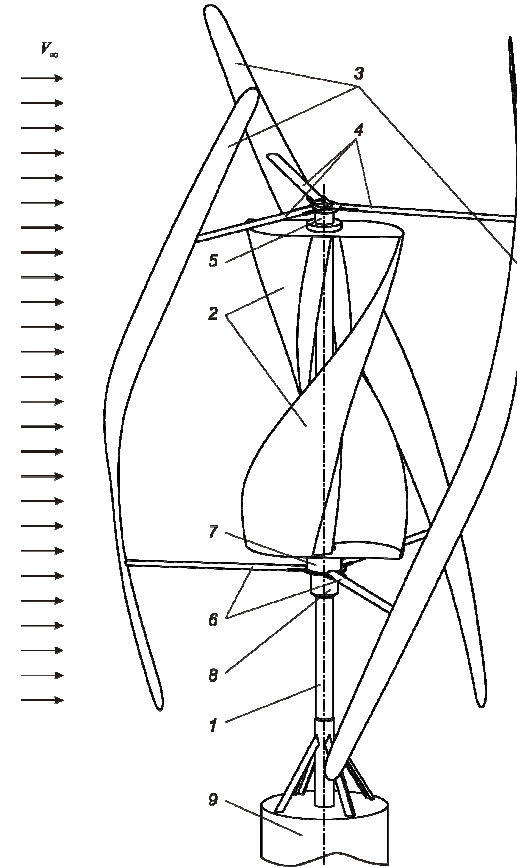
(diametrul rotorului $D = 4m$, înălțimea submersată a palei $h = 1,4m$, lungimea cordului palei $l = 1,3 m$) (MHCF D4x1,5 ME)

Turbină de vânt cu pale elicoidale



Avantaje:

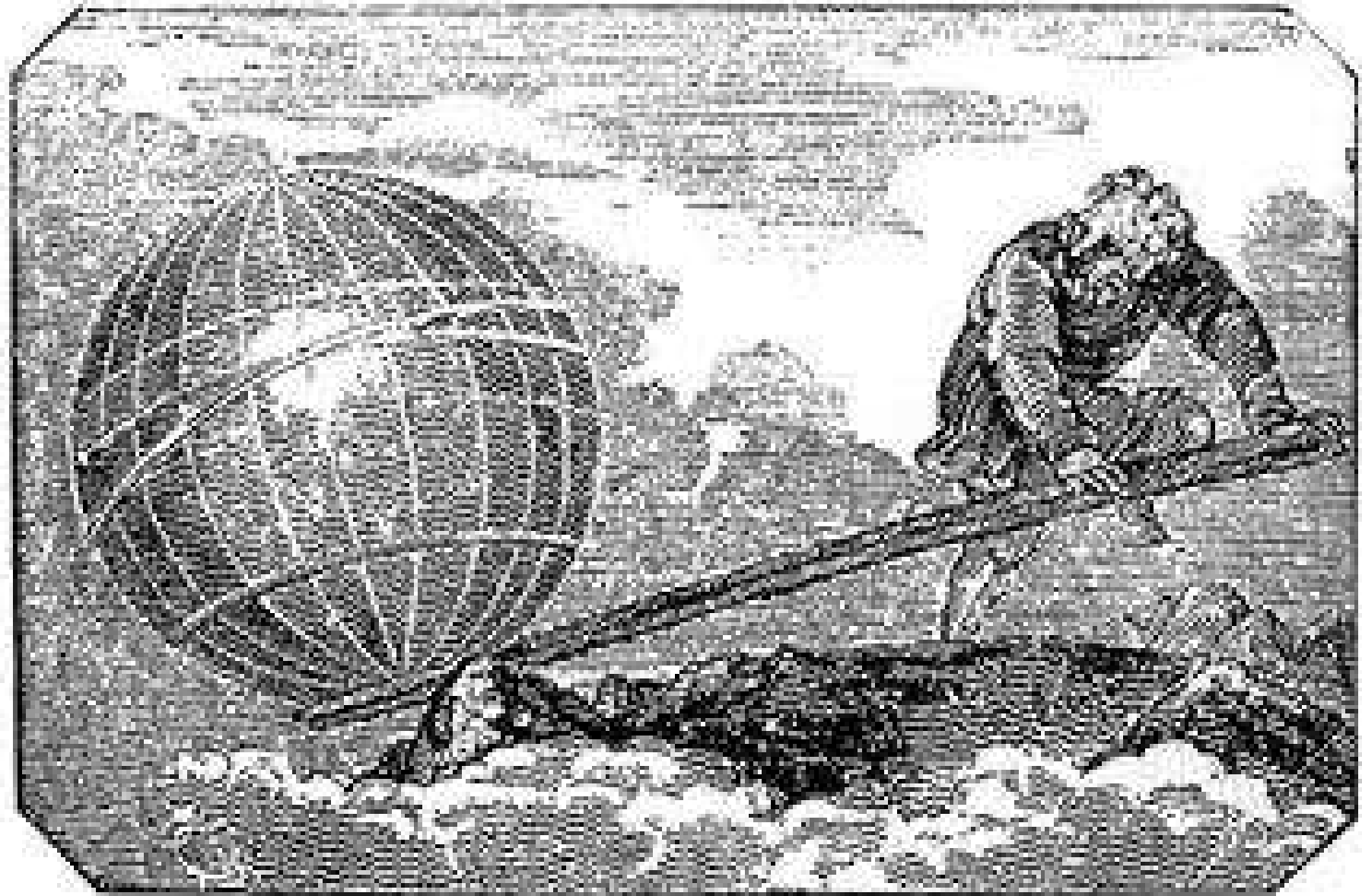
- majorarea coeficientului de utilizare a energiei eoliene;
- uniformitatea rotirii organului de lucru;
- zgomot și vibrații reduse.



Conclusions

- Development of cost-effective technologies and promising nanomaterials;
- Progress in developing semiconductor nanotemplates for nanofabrication;
- Pronounced tendencies in diminishing the diameter of glass-coated metal microwires and fabrication of ordered arrays of metal nanowires;
- Elaboration of metal-semiconductor and polymer-semiconductor nanocomposites for optoelectronic applications;
- Development of new laser materials and rare-earth-doped fiber amplifiers;
- Growth and characterization of magnetic materials;
- Building of new coordination and supramolecular polyfunctional compounds;
- Photothermoplastic recording as a tool of color imaging using vitreous chalcogenide semiconductors as photosensitive layers;
- Elaboration and characterization of novel device structures.

Knowledge moves the world



Thank you
for your kind attention!